

Acoustic-mechanic modeling of  
polydimethylsiloxane in the MHz regime  
for metamaterials applications

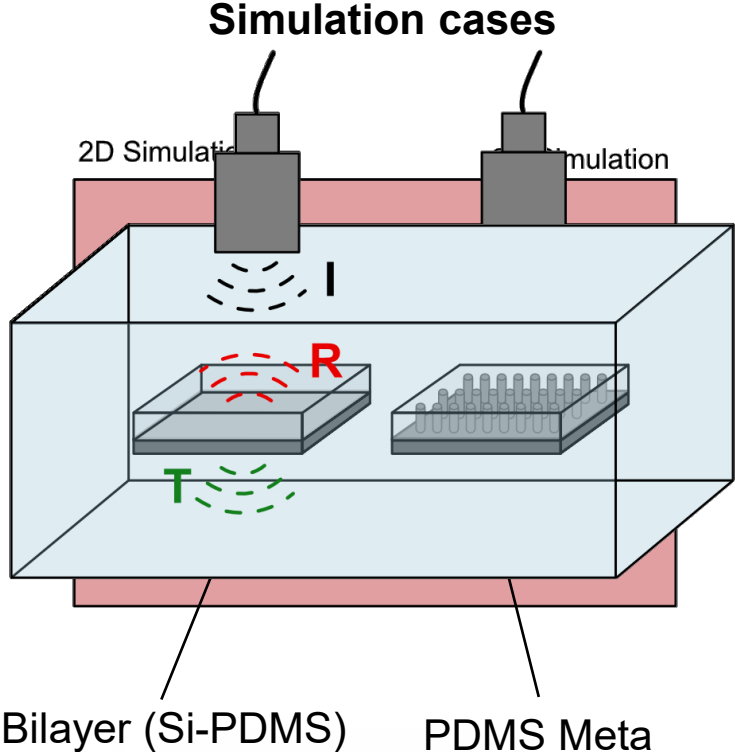
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Micro- and Nanosystems

Comsol Conference 2023

Bilayer used as **reference** to compare simulation with analytical solution

### 2D simulation:

- Multiphysics (Solid Mechanics & Pressure Acoustics)
- Parametric ( $f$ ) frequency domain



$$R = \prod_{j=1}^n (Z_{in}^j + Z_j) / (Z_{in}^j + Z_{j+1}) e^{i\varphi_j}$$

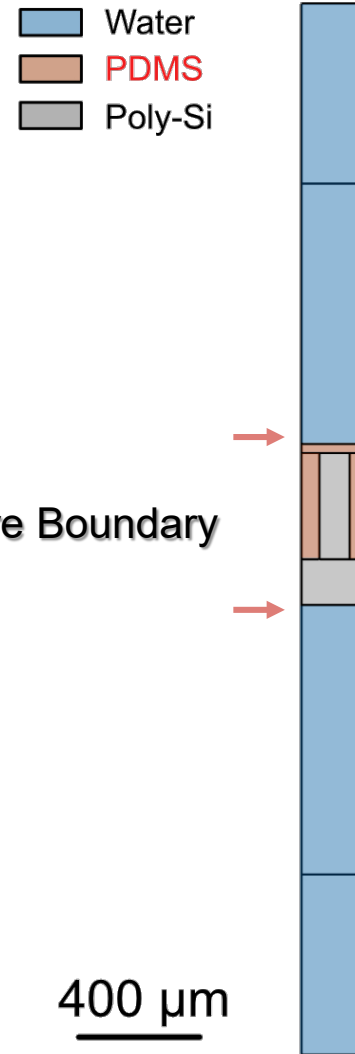
LM Brekovski, *Waves in Layered Media*, 1980, Academic Press

## Solid Mechanics

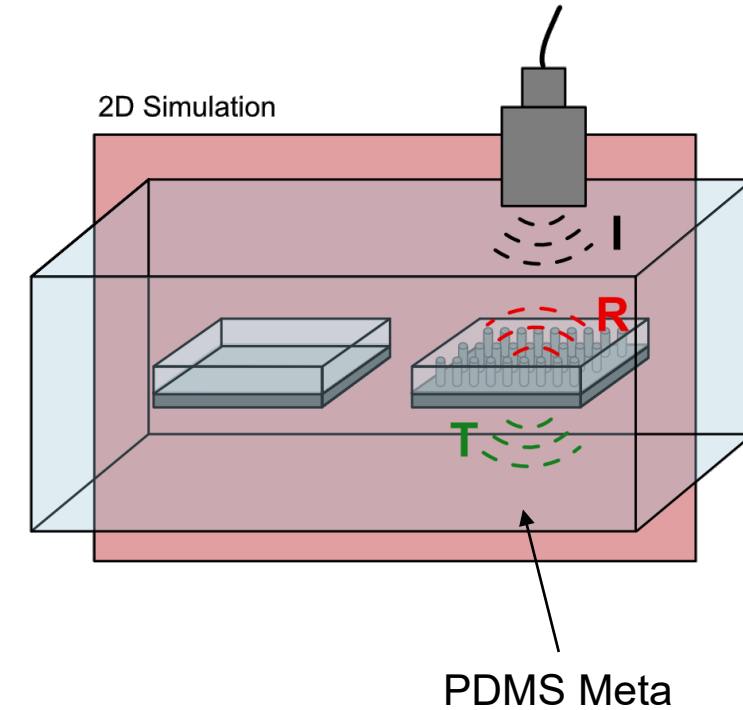
- Poly-Silicon: built-in material
- PDMS: **experimental ( $f, T$ )**

## Pressure Acoustics

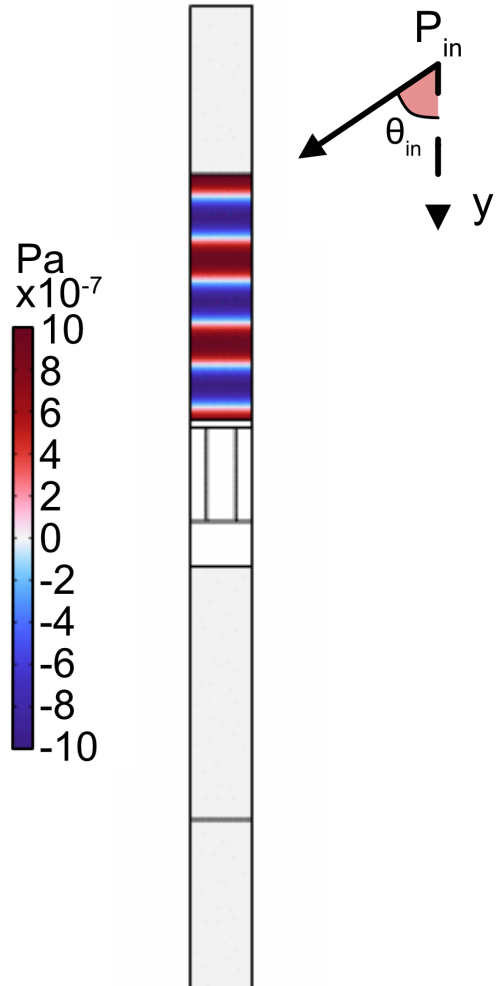
- Water: built-in material



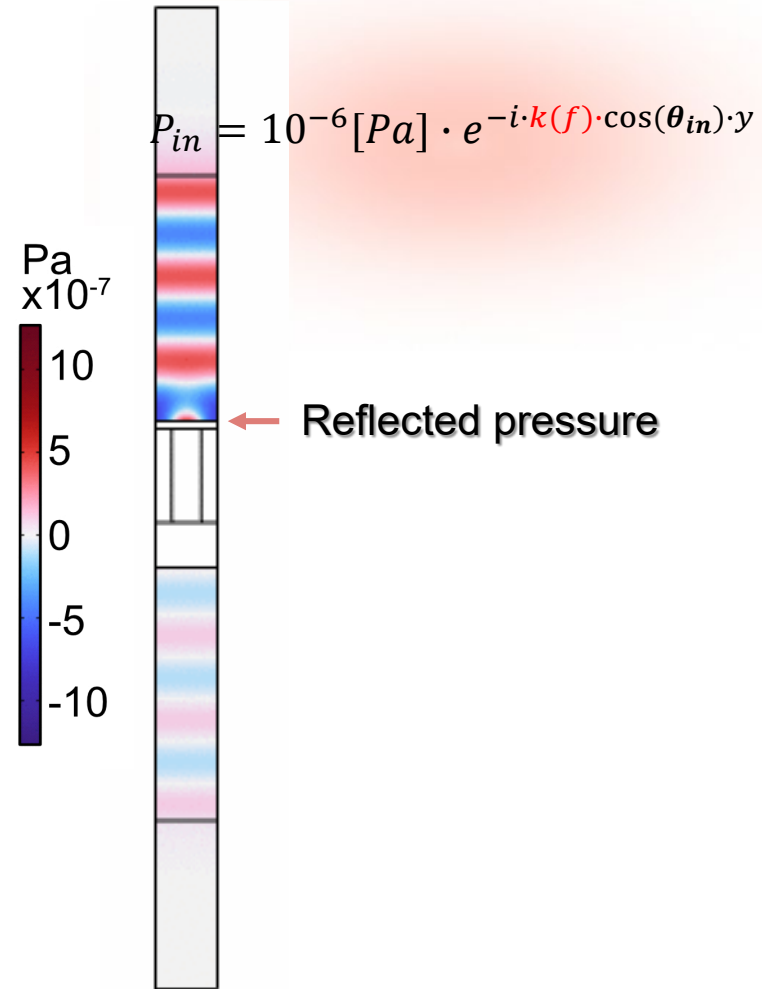
## Simulation cases



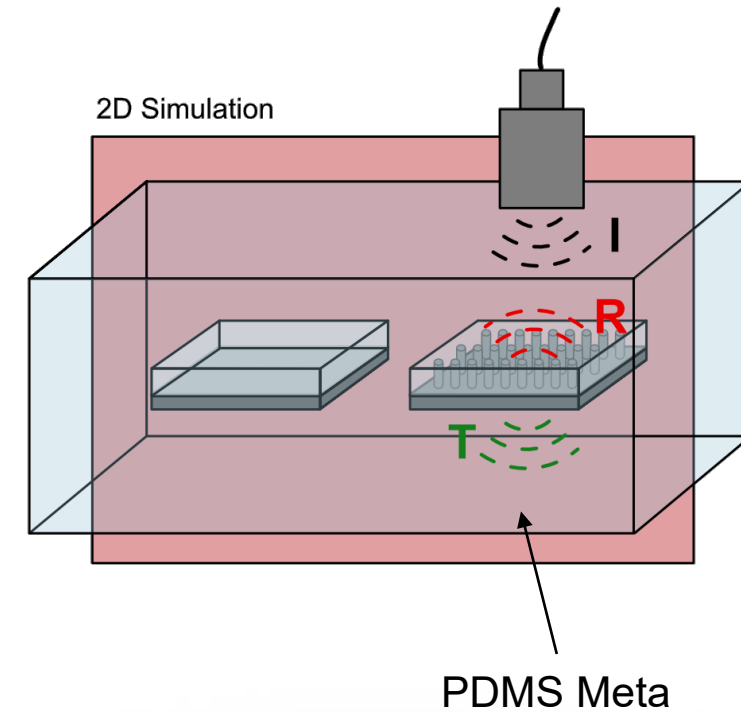
### Incoming pressure



### Scattered pressure

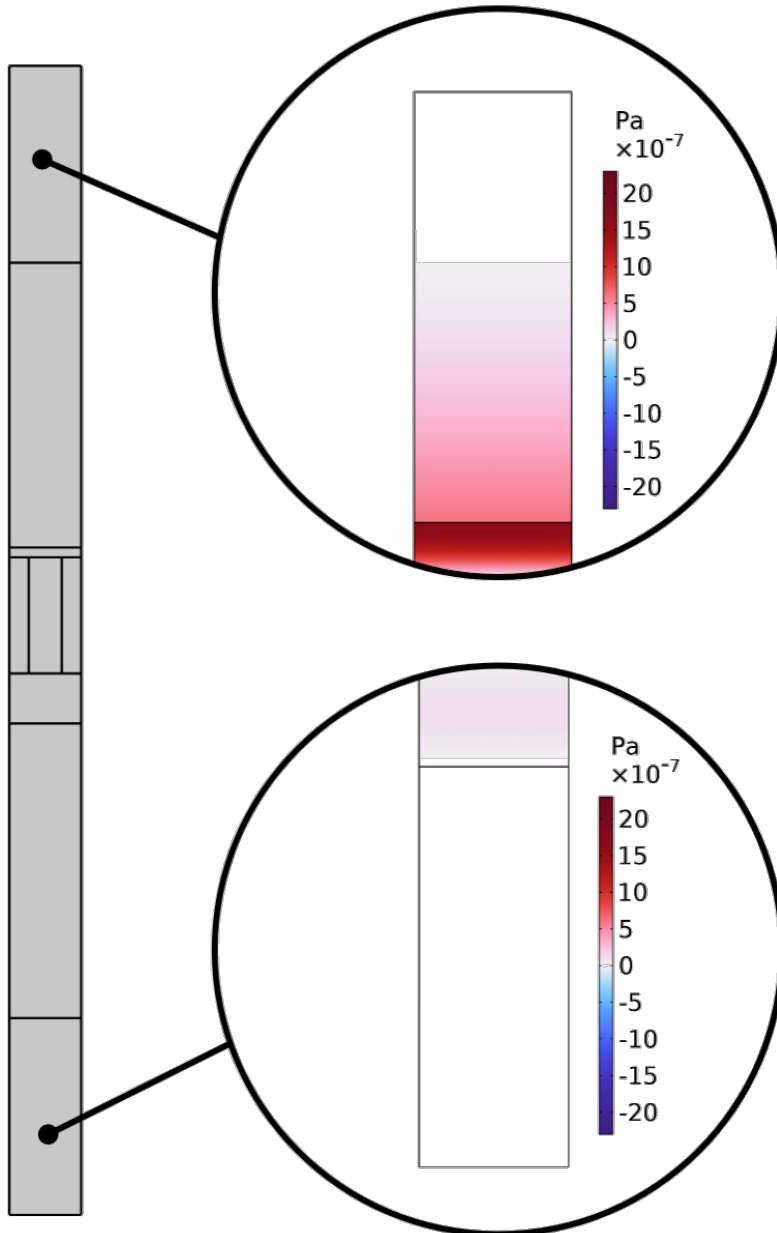


### Simulation cases



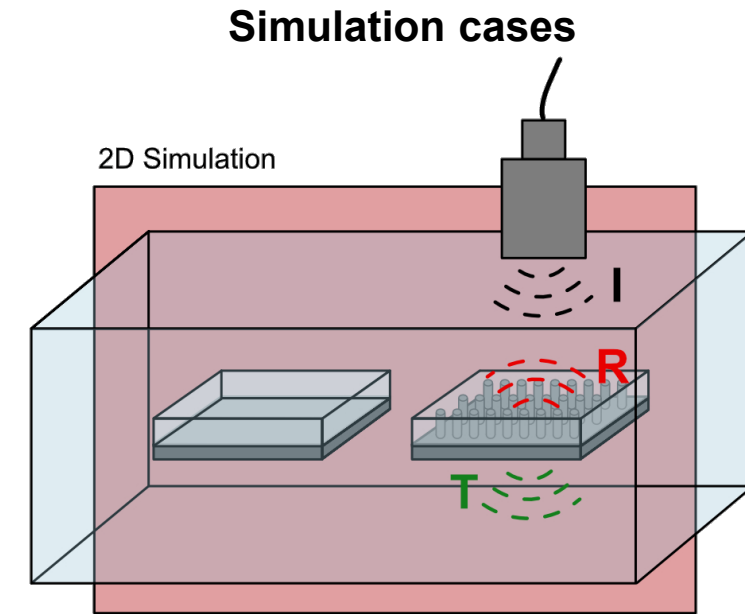
$$|R_{dB}| = 20 \cdot \log_{10} \left( \left| \frac{P_s}{P_{in}} \right| \right)$$

# Simulation: PDMS Meta



## Perfectly Matched Layers:

- Coordinate stretching type: Rational
- Type: Cartesian (unitary scaling factor)

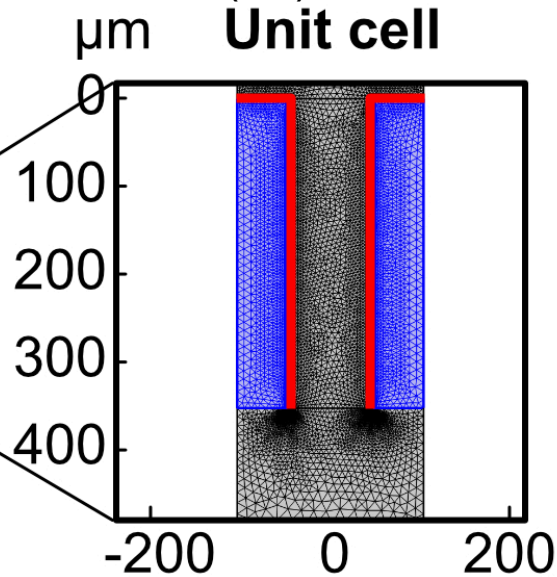


**Boundary conditions:**  
Floquet periodicity



## Free triangular mesh:

- Maximum element size:  $\left(\frac{c_{L,water}}{f}\right) \cdot \frac{1}{N}$
- N(=6) conservative factor



## PDMS domain mesh:

- Edge mesh
- Maximum element size:  $\left(\frac{c_{S,PDMS}}{f}\right) \cdot \frac{1}{N}$
- Boundary layers: 20

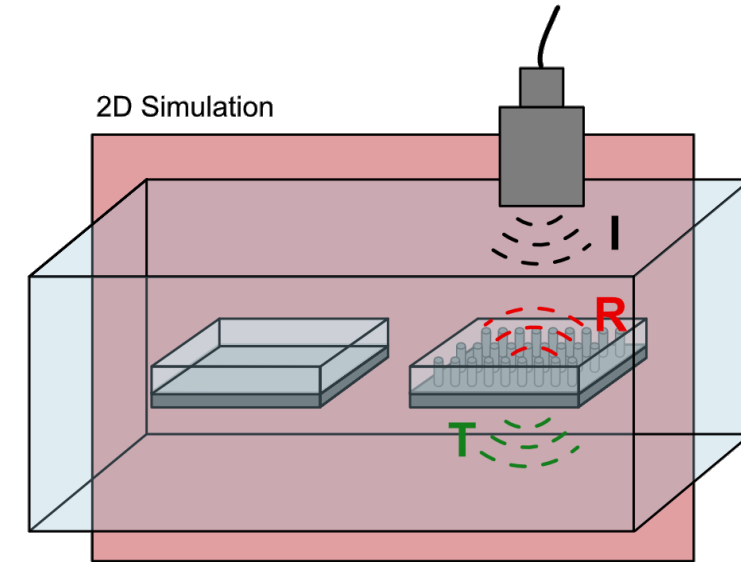
## Poly-Si domain mesh:

- Free triangular
- Maximum element size:  $\left(\frac{c_{L,Si}}{f}\right) \cdot \frac{1}{N}$

## Mapped mesh (PML):

- Distribution type: fixed number of elements
- Number of elements: 8

## Simulation cases



Shear waves at the interface  
PDMS-Si due to BCs

$c_s$  = shear wave speed  
 $c_L$  = longitudinal wave speed

# Frequency dependency of PDMS

## Solid Mechanics

$$\begin{pmatrix} \sigma_1 \\ \sigma_2 \\ \sigma_3 \\ \sigma_4 \\ \sigma_5 \\ \sigma_6 \end{pmatrix} = \begin{pmatrix} C_{11} & C_{12} & C_{12} & 0 & 0 & 0 \\ C_{12} & C_{11} & C_{12} & 0 & 0 & 0 \\ C_{12} & C_{12} & C_{11} & 0 & 0 & 0 \\ 0 & 0 & 0 & C_{44} & 0 & 0 \\ 0 & 0 & 0 & 0 & C_{44} & 0 \\ 0 & 0 & 0 & 0 & 0 & C_{44} \end{pmatrix} \begin{pmatrix} \varepsilon_1 \\ \varepsilon_2 \\ \varepsilon_3 \\ \varepsilon_4 \\ \varepsilon_5 \\ \varepsilon_6 \end{pmatrix}$$

Hypothesis: isotropic material

L- and S-waves velocities related to elastic constants:

$$C_{11}(f) = \rho_P \hat{c}_L^2, \quad C_{44}(f) = \rho_P \hat{c}_S^2$$

$$\hat{c}_i(f) = \frac{2\pi f}{2\pi f/c_i + j\alpha_i} \quad \text{with } i = L \text{ or } S$$

Elastic constants relation:

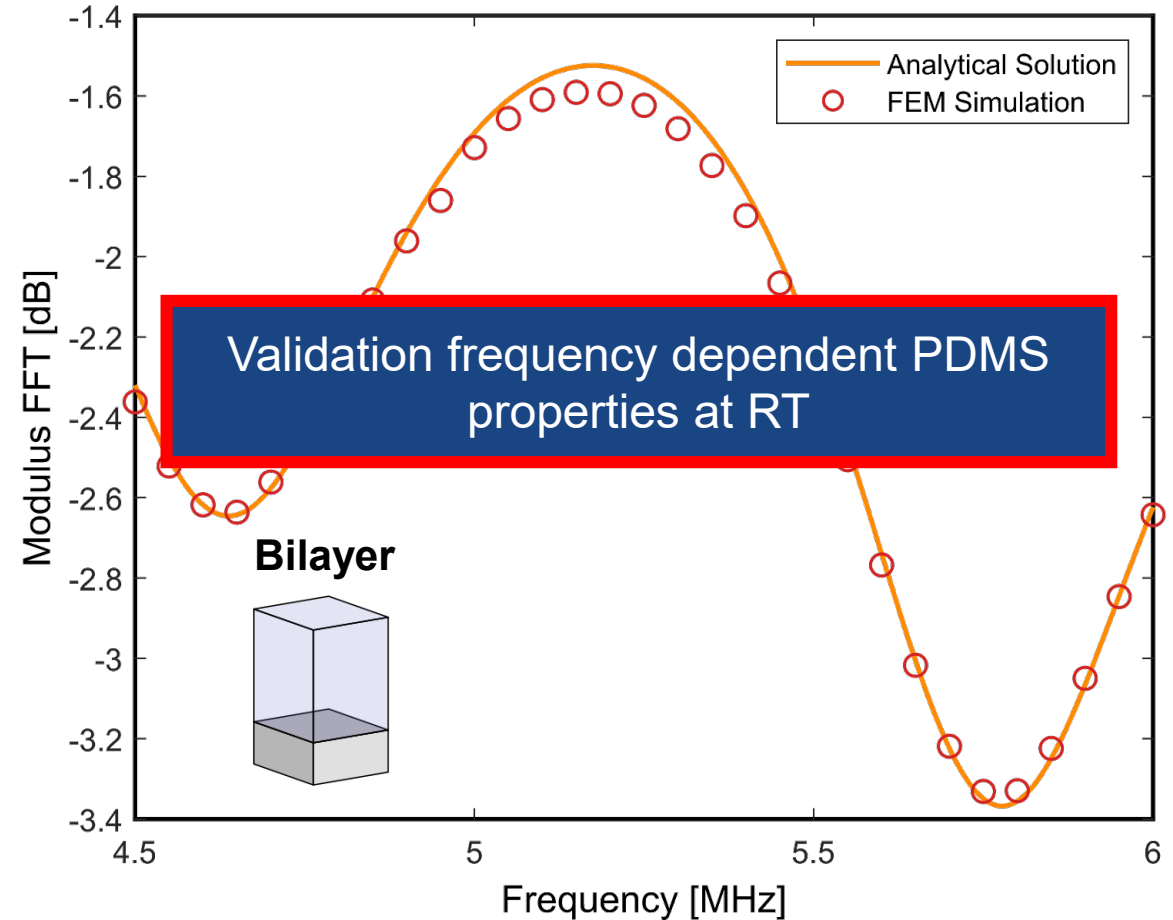
$$C_{12}(f) = C_{11}(f) - 4C_{44}(f)$$

$$C_{11}(f) = K + \frac{4}{3}G$$

$$C_{44}(f) = G$$

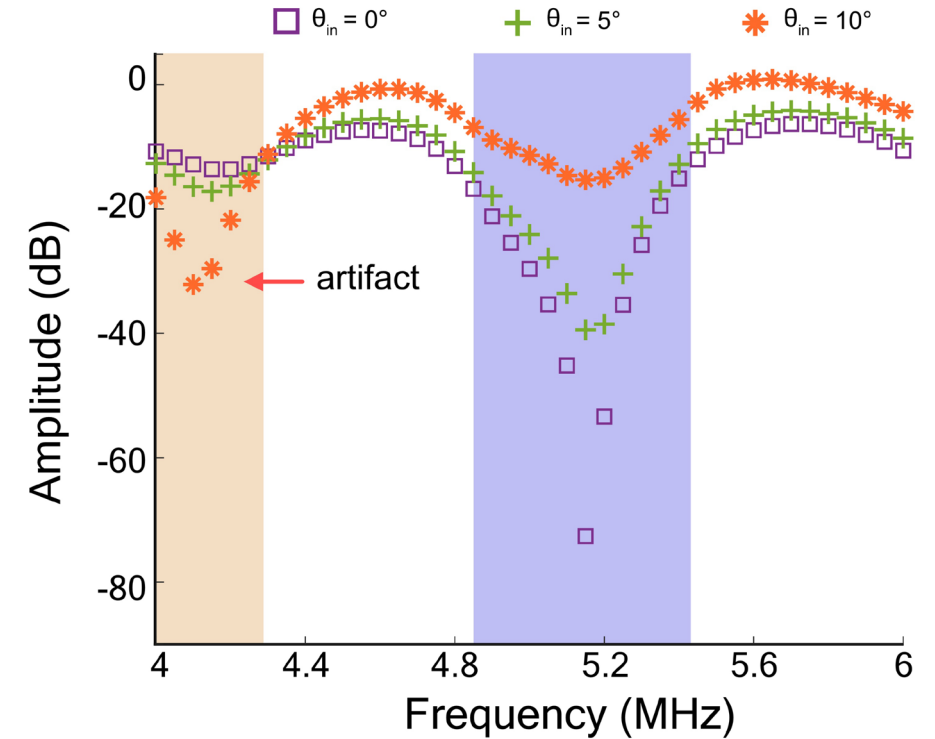
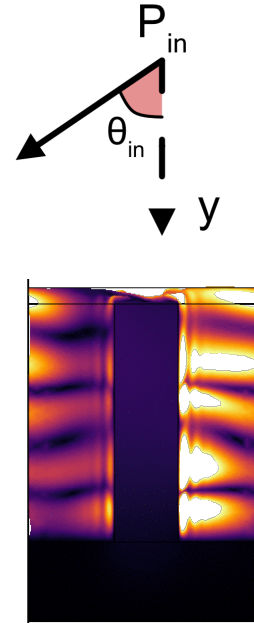
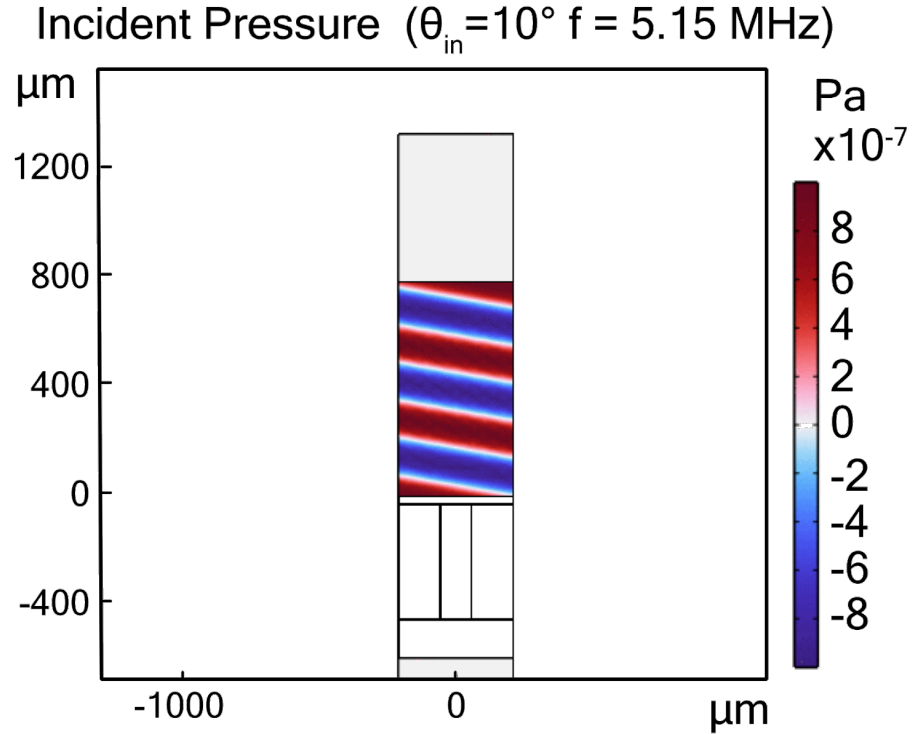
- Linear elastic material
- Specify: Bulk and Shear Modulus

- Experimental elastic constants @RT (interpolated from [1])
- Analytical solution vs FEM simulation with complex PDMS material properties



[1] NR Skov et al., *Physical Review Applied* 12, 2019  
 [2] G Xu et al., *Physical Review Applied* 13, 2020

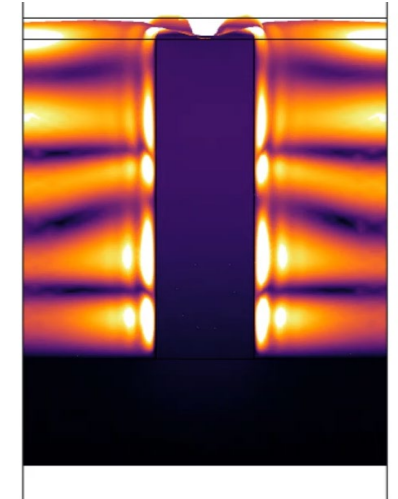
# Application: incidence angle



**Asymmetric** stress distribution in the PDMS generating spurious peaks and **artifacts** in the reflection spectrum



- ✓ Successful implementation of **temperature** and **frequency** dependent acoustic properties of **PDMS** (MHz regime)
- ✓ Validation with simpler **analytical** models and **experiments**
- ✓ Material definition can be used for other bio-applications
  - Investigation of artifacts potentially arising in our experiments (incoming pressure field misalignment)
  - Investigation of fabrication process variation (not shown in this presentation)
- 3D implementation **computationally limited**
  - Investigation of **cluster-based** solutions



# Acknowledgements

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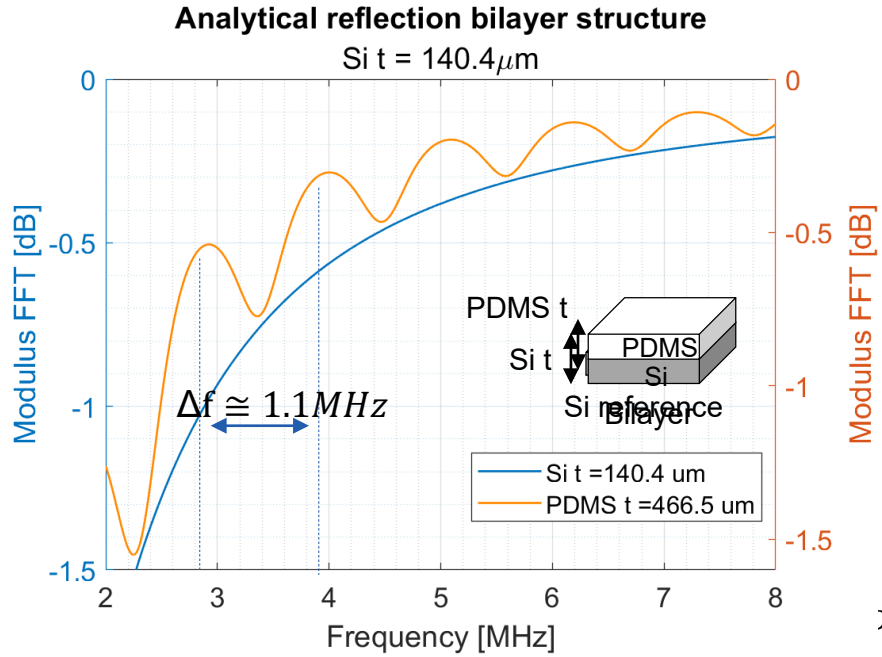
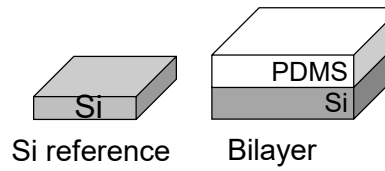
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- Adrien Toros



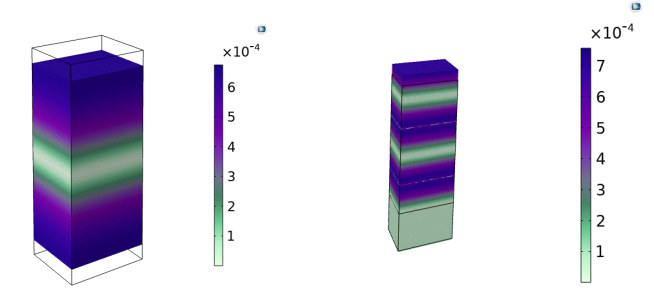
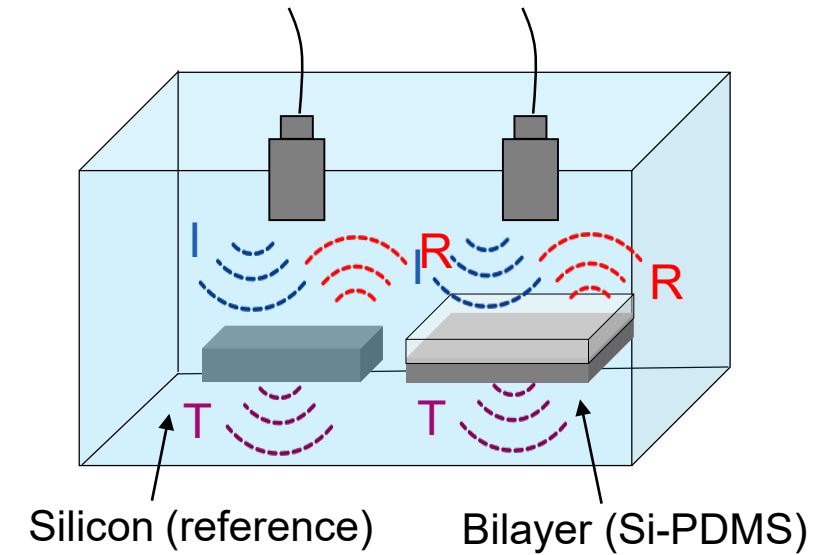
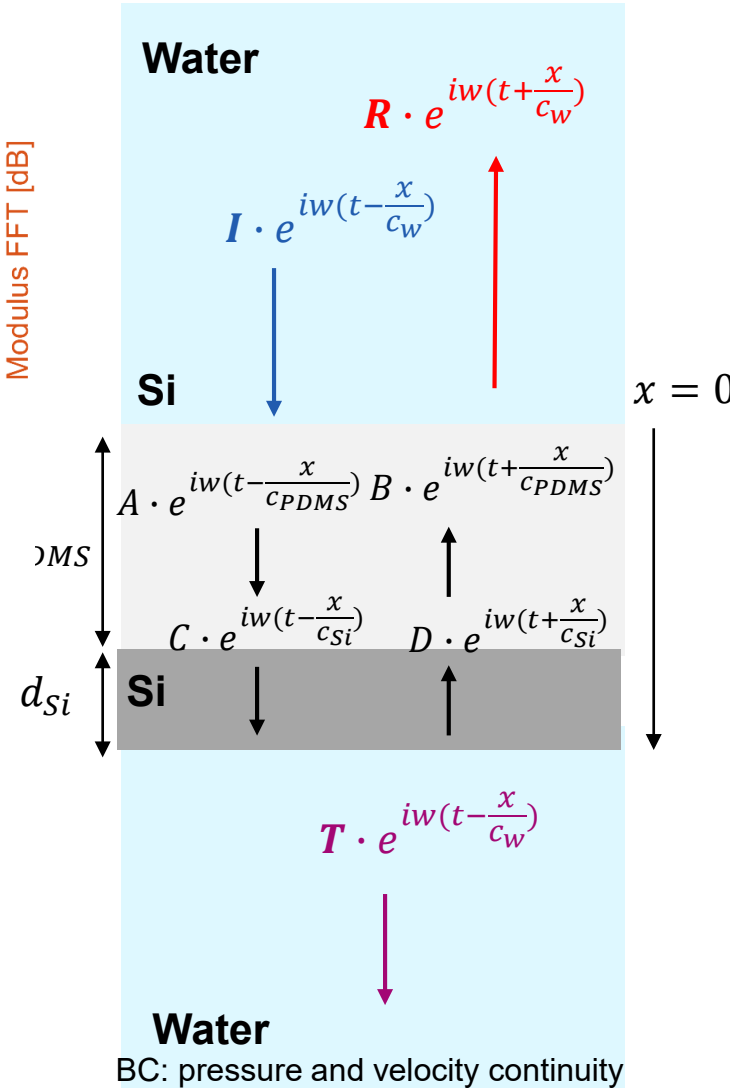
# Silicon reference vs bilayer



$$R_{dB} = 20 \log_{10} \left( \alpha \cdot \frac{i \cdot \tan(k_0 d) \cdot (Z_0^2 - Z_1^2)}{i \cdot \tan(k_0 d) \cdot (Z_0^2 + Z_1^2) - 2Z_0 Z_1} \right)$$

- Impedance matching condition for  $f = \frac{(n+1) \cdot c}{2 \cdot d}$

$$f_{0,Si} \approx 28.4 \text{ MHz} \prod_{j=1}^n \frac{Z_{i0}^j f_{j+1} + Z_{i0}^j}{Z_{i0}^j f_{j+1} - Z_{i0}^j} \quad (Z_{i0}^j \approx 1.1 \text{ MHz})$$



- Only longitudinal waves considered
- Neglected attenuation and dispersion

LM Brekovski, *Waves in Layered Media*, 1980, Academic Press

